

# Improvement of the $\gamma$ -TiAl Oxidation Resistance by Aluminizing

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### Introduction

In combination with good stiffness and strength, titanium aluminides offer the potential for component weight savings on the order of 50% over superalloys and steels. The target application temperature range for Ti-Al intermetallics is 600-1000°C. However, the use of TiAl based components above 800°C is limited especially by their poor environmental resistance. The present study deals with aluminizing as a possible method for improving  $\gamma$ -TiAl high-temperature oxidation resistance.

## **Experimental procedure**

The pack-cementation coating process was used to aluminize the surface region of a  $\gamma$ -TiAl alloy to a potential alumina-forming phase. Coating was formed by burying y-TiAl coupons for 5 h at 800°C in a powder mixture consisting of 5 wt.% Al, 0.5 wt.% NH<sub>4</sub>Cl, and balance Al<sub>2</sub>O<sub>3</sub>. The aluminized samples were tested at 800, 900 and 1000°C in laboratory air for up to 100 h.

800°C / 10 h / air

 $\alpha + \theta - A |_{0} O_{1}$ 

TiAL,

6,5 6

5,5 5 4,5 (n.a.)

4

3,5

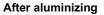
2.5

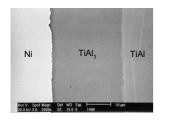
sity f

TiAl

TiAL

TiO





The aluminizing treatment resulted in the formation of a 30 µm thick adherent and free of cracks TiAl<sub>3</sub> layer. This layer interdiffused rapidly with the  $\gamma$ -TiAl substrate during oxidation, leading to the formation of a TiAl<sub>2</sub> layer at the oxide/TiAl<sub>3</sub> interface

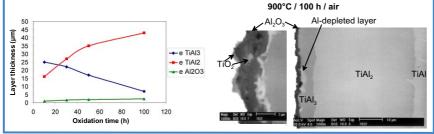
The TiAl<sub>3</sub> coating on  $\gamma$ -TiAl showed excellent oxidation resistance in air at 900 and 1000°C for 10 h, forming a protective and adherent Al<sub>2</sub>O<sub>3</sub> scale. At 800°C, the oxidation process induced the formation of a thicker  $AI_2O_3$  scale containing TiO<sub>2</sub> grains. At 800, 900, and 1000°C, the oxide was  $\alpha {+}\theta {-} AI_2O_3$  as confirmed by Fluorescence spectroscopy analysis.

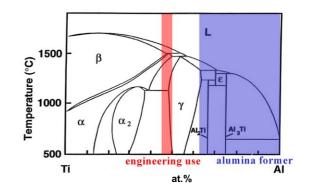
## Oxidation behavior of TiAl<sub>3</sub> and TiAl<sub>2</sub> phases

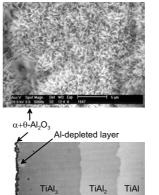
To study the oxidation behavior of the different TiAl phases, a short term oxidation test was performed at 900°C on the cross section of the  $\gamma$ -TiAl substrate coated and oxidized at 900°C for 10 h in air. Surprisingly, the  $\alpha$ -Al<sub>2</sub>O<sub>3</sub> scale formed on the TiAl<sub>2</sub> phase was significantly thinner and free of whiskers compared to the metastable  $\theta$ -Al2O3 formed on the most promising oxidation resistant TiĀl<sub>3</sub> phase.

### 100 h oxidation at 900°C in air

When the oxidation time was prolonged to 100 h, both the oxidation and interdiffusion processes induced a decrease of the TiAl<sub>3</sub> layer thickness and an increase of the TiAl<sub>2</sub> layer thickness. From 10 to 50 h exposure time, the oxide scale was only composed of  $Al_2O_3$ . After 100 h oxidation, the alumina-forming TiAl<sub>3</sub> layer was only 7  $\mu m$  thick, and some TiO<sub>2</sub> grains were formed in the Al<sub>2</sub>O<sub>3</sub> layer.



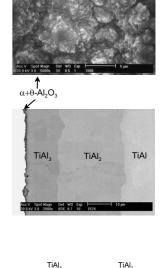


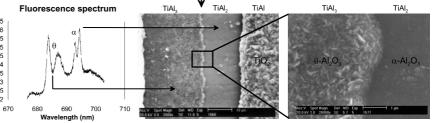


After oxidation

900°C / 10 h / air

1000°C / 10 h / air





900°C / 1 h / air

## Conclusion

- An adherent oxidation resistant Al-diffusion coating was successfully formed on the surface of a  $\gamma\text{-TiAl}$  alloy using the pack-cementation technique. The protection was provided by aluminizing of the  $\gamma$ -TiAl substrate to its highest aluminide, the alumina-forming TiAl<sub>3</sub> phase.
- After 10 h oxidation at 900 and 1000°C in air, a protective and adherent Al<sub>2</sub>O<sub>3</sub> layer identified as  $\alpha + \theta$  phase was formed on the TiAl<sub>3</sub> coating. The effectiveness of the TiAl, coating was seriously affected by the TiAl<sub>2</sub> phase which develops during oxidation, and after 100 h oxidation at 900°C in air, the formation of a protective Al2O3 layer was no longer maintained.

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